

Pb Free Plating Product

APT30D120BG



30 Ampere, 1200V Switch Mode Single Fast Recovery Epitaxial Diode

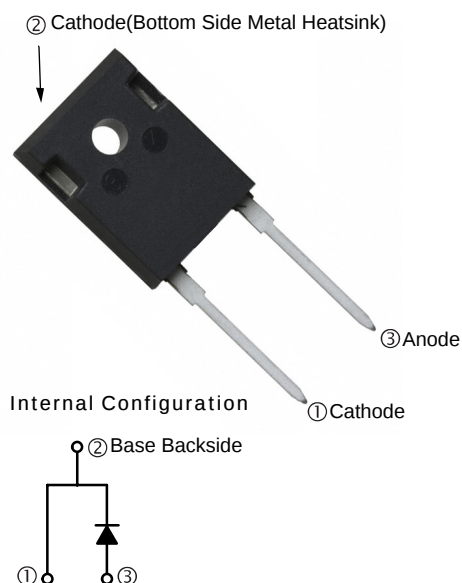
APPLICATION

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS

PRODUCT FEATURE

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- Low Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Leakage Current

TO-247-2L



GENERAL DESCRIPTION

APT30D120BG using the latest FRED FAB process (planar passivation pellet) with ultrafast and soft recovery characteristics.

ABSOLUTE MAXIMUM RATINGS

 $T_C = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V_R	Maximum D.C. Reverse Voltage		1200	V
V_{RRM}	Maximum Repetitive Reverse Voltage		1200	V
$I_{F(AV)}$	Average Forward Current	$T_C = 110^\circ\text{C}$	30	A
$I_{F(RMS)}$	RMS Forward Current	$T_C = 110^\circ\text{C}$	42	A
I_{FSM}	Non-Repetitive Surge Forward Current	$T_J = 45^\circ\text{C}$, $t = 10\text{ms}$, 50Hz, Sine	300	A
P_D	Power Dissipation		115	W
T_J	Junction Temperature		-40 to +150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		-40 to +150	$^\circ\text{C}$
Torque	Module-to-Sink	Recommended (M3)	1.1	N·m
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case	1.1	$^\circ\text{C/W}$
Weight			7.0	g

ELECTRICAL CHARACTERISTICS

 $T_C = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R = 1200\text{V}$	--	--	100	μA
		$V_R = 1200\text{V}$, $T_J = 125^\circ\text{C}$	--	--	1	mA
V_F	Forward Voltage	$I_F = 30\text{A}$	--	2.15	2.5	V
		$I_F = 30\text{A}$, $T_J = 125^\circ\text{C}$	--	1.75	--	V
t_{rr}	Reverse Recovery Time	$I_F = 1\text{A}$, $V_R = 30\text{V}$, $di_F/dt = -200\text{A}/\mu\text{s}$	--	30	--	ns
t_{rr}	Reverse Recovery Time	$V_R = 600\text{V}$, $I_F = 30\text{A}$	--	160	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt = -200\text{A}/\mu\text{s}$, $T_J = 25^\circ\text{C}$	--	5	--	A
t_{rr}	Reverse Recovery Time	$V_R = 600\text{V}$, $I_F = 30\text{A}$	--	300	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt = -200\text{A}/\mu\text{s}$, $T_J = 125^\circ\text{C}$	--	11	--	A

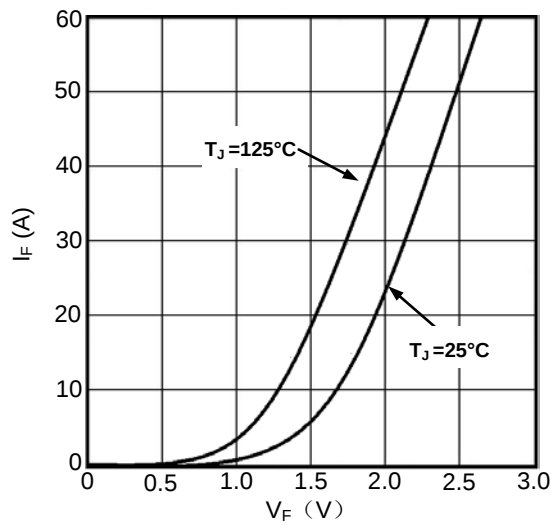


Fig1. Forward Voltage Drop vs Forward Current

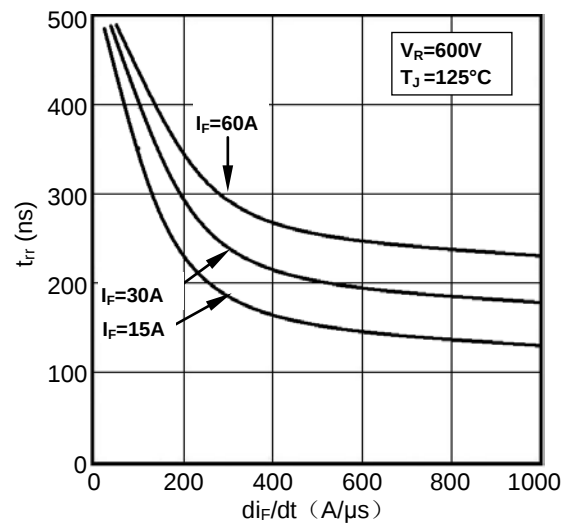


Fig2. Reverse Recovery Time vs di_F/dt

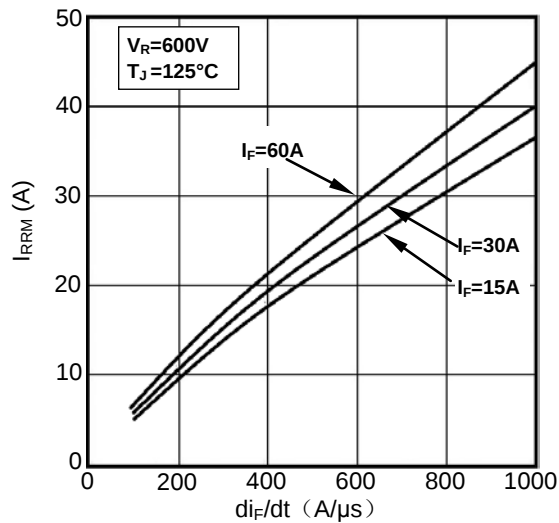


Fig3. Reverse Recovery Current vs di_F/dt

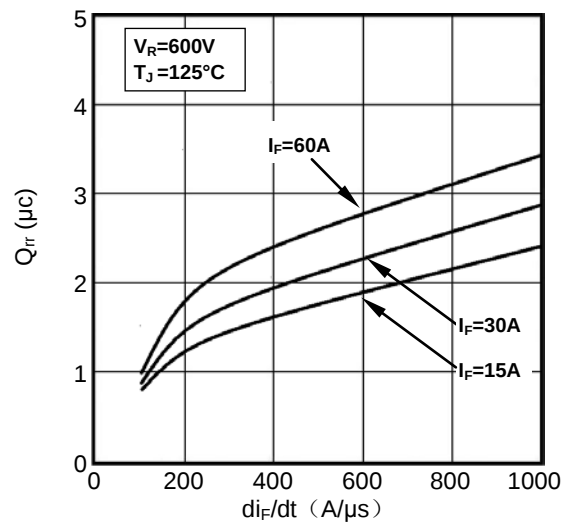


Fig4. Reverse Recovery Charge vs di_F/dt

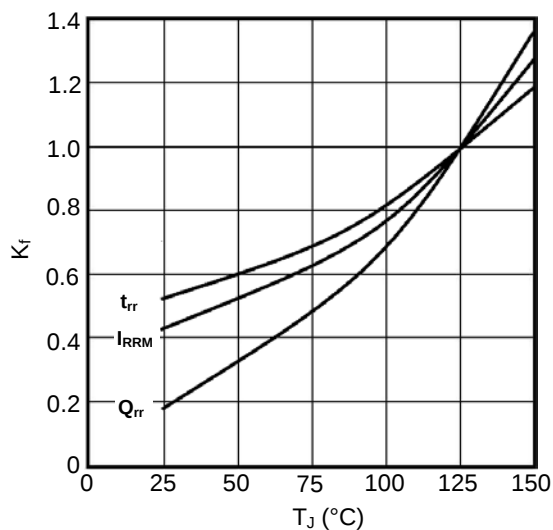


Fig5. Dynamic Parameters vs Junction Temperature

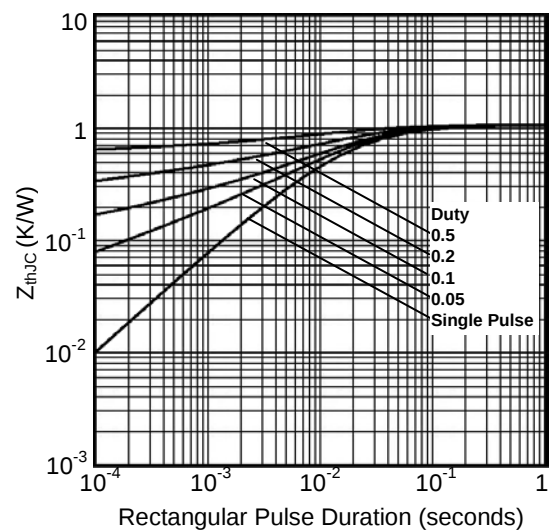


Fig6. Transient Thermal Impedance

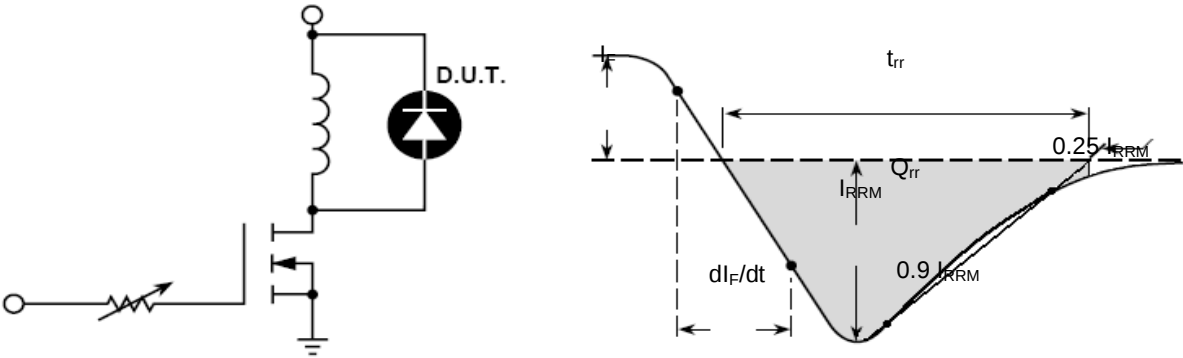
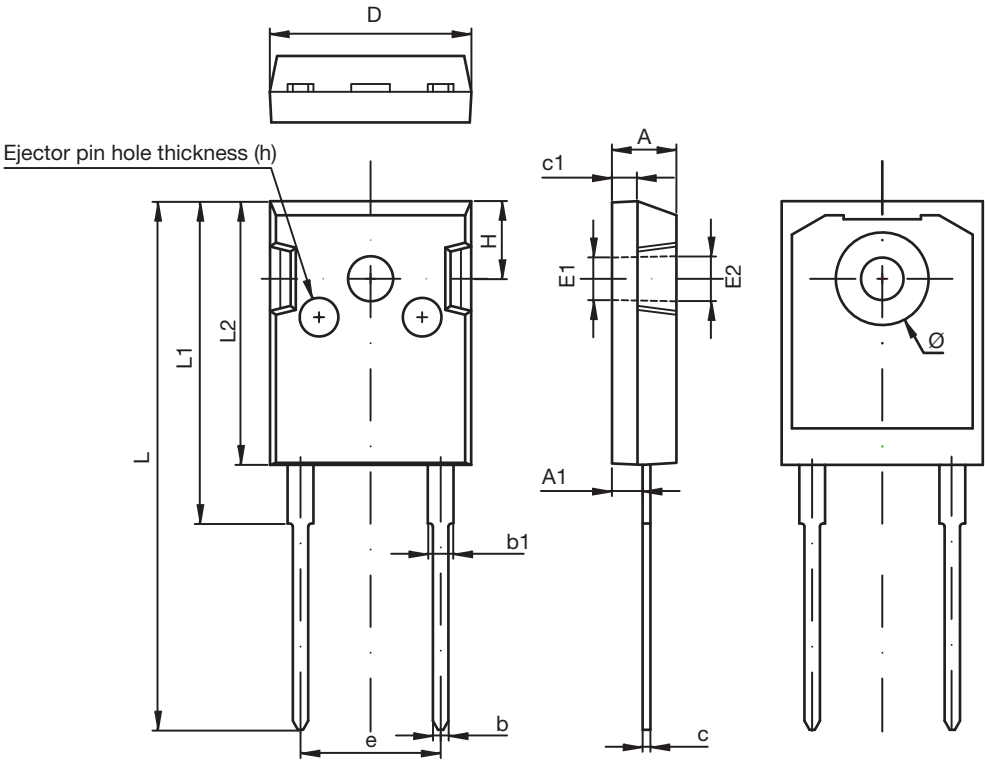


Fig7. Diode Reverse Recovery Test Circuit and Waveform



TO-247-2L DIMENSIONS

SYMBOL	DIMENSIONS IN MILLIMETERS		DIMENSIONS IN INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 Ref.		0.138 Ref.	
E2	3.600 Ref.		0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
e	10.900 Typ.		0.429 Typ.	
H	5.980 Typ.		0.235 Typ.	
h	0.000	0.300	0.000	0.012